This listing of claims will replace all prior versions, and listings, of claims in the

application:

Listing of Claims:

Claim 1 (canceled).

Claim 2 (previously presented). A method for generating a periodic circular

structure in a basic support material comprising the steps of:

a) generating a plurality of diffraction masks such that each mask includes at

least one transmission diffraction grating having at least one pattern selected

from the group consisting of a periodic concentric circular pattern, a spiral-like

periodic pattern and a periodic radial spoke pattern;

b) positioning the plurality of the diffraction masks simultaneously or

successively at a certain distance from the basic support material to be

patterned, the distance being mask dependent;

c) exposing the basic support material by directing light beams through each of

the plurality of the diffraction masks; and

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d) interfering the different light beams diffracted by the grating on each mask in

order to generate coincident light intensity patterns on the surface of the basic

support material;

wherein the step of exposing further comprises the steps of: generating

exposure by directing light through a transmission diffraction mask having a

periodic circular interference mask pattern so as to generate exposure of

circular tracks on the basic support material; and after said step of generating

exposure further generating exposure using a transmission diffraction mask

having a spiral extending interference mask pattern or a radial extending

interference mask pattern thereby generating a circumferential partitioning of

said generated circular tracks.

Claim 3 (previously presented). A method for generating a periodic circular

structure in a basic support material comprising the steps of:

a) generating a plurality of diffraction masks such that each mask includes at

least one transmission diffraction grating having at least one pattern selected

from the group consisting of a periodic concentric circular pattern, a spiral-like

periodic pattern and a periodic radial spoke pattern;

b) positioning the plurality of the diffraction masks simultaneously or

successively at a certain distance from the basic support material to be

patterned, the distance being mask dependent;

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c) exposing the basic support material by directing light beams through each of

the plurality of the diffraction masks; and

d) interfering the different light beams diffracted by the grating on each mask in

order to generate coincident light intensity patterns on the surface of the basic

support material;

wherein the step of exposing further comprises the steps of: generating said

exposure using a first transmission diffraction mask having a combined circular

and spiral interference mask pattern so as to generate a first spiral track pattern

on the basic support material; and after said step of generating said exposure

further generating said exposure using a second transmission diffraction mask

having a combined circular and spiral extending interference mask pattern

wherein said spiral component is oriented in an opposite direction to the first

transmission diffraction mask, the second transmission effecting a partitioning

of said generated first spiral track pattern by intersecting said first and said

second spiral track pattern.

Claim 4 (currently amended). The method according to claim 1 claim 2, wherein

the diffraction masks are one of an absorption and phase shifting mask.

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Claim 5 (currently amended). The method according to claim 1 claim 2, wherein the light source generates light having a circular polarization or a linear polarization which varies with time.

Claim 6 (currently amended). The method according to claim 1 claim 2, wherein the light source comprises a wavelength between 5 and 500 nanometers.

Claim 7 (original). The method according to claim 6, further comprising the step of using an immersion lithography process for decreasing feature sizes, the lithography process having a refractive index larger than 1 and disposed between the transmission diffraction mask and the basic support material.

Claim 8 (currently amended). The method according to claim 1 claim 2, wherein the partitioned circular periodic structure comprises cells having a length to width ratio larger than 1.

Claim 9 (currently amended). The method according to claim 1 claim 2, wherein the basic support material comprises a layer for magnetic bit cells for a magnetic storage device.